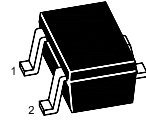
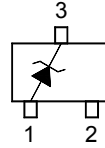


MMBZ5221BW~MMBZ5259BW

SILICON PLANAR ZENER DIODES



SOT-323 Plastic Package

1. Anode 3. Cathode

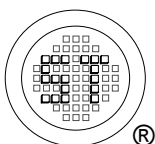
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Power Dissipation	P_D	200	mW
Operating Junction and Storage Temperature Range	T_j, T_s	- 65 to + 150	$^\circ\text{C}$

Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise noted, $V_F < 0.9\text{ V}$ at $I_F = 10\text{ mA}$)

Type	Marking Code	Zener Voltage Range ¹⁾			Dynamic Resistance			Reverse Leakage Current	
		V_{Znom}	I_{ZT}	for V_{ZT}	Z_{ZT}	Z_{ZK}	at I_{ZK}	I_R	at V_R
		V	mA	V	Max. (Ω)	Max. (Ω)	mA	Max. (μA)	V
MMBZ5221BW	HA	2.4	20	2.28...2.52	30	1200	0.25	100	1
MMBZ5223BW	HB	2.7	20	2.57...2.84	30	1300	0.25	75	1
MMBZ5225BW	HC	3	20	2.85...3.15	30	1600	0.25	50	1
MMBZ5226BW	HD	3.3	20	3.14...3.47	28	1600	0.25	25	1
MMBZ5227BW	HE	3.6	20	3.42...3.78	24	1700	0.25	15	1
MMBZ5228BW	HF	3.9	20	3.71...4.1	23	1900	0.25	10	1
MMBZ5229BW	HH	4.3	20	4.09...4.52	22	2000	0.25	5	1
MMBZ5230BW	HJ	4.7	20	4.47...4.94	19	1900	0.25	5	2
MMBZ5231BW	HK	5.1	20	4.85...5.36	17	1600	0.25	5	2
MMBZ5232BW	HM	5.6	20	5.32...5.88	11	1600	0.25	5	3
MMBZ5234BW	HN	6.2	20	5.89...6.51	7	1000	0.25	5	4
MMBZ5235BW	HP	6.8	20	6.46...7.14	5	750	0.25	3	5
MMBZ5236BW	HR	7.5	20	7.13...7.88	6	500	0.25	3	6
MMBZ5237BW	HX	8.2	20	7.79...8.61	8	500	0.25	3	6.5
MMBZ5239BW	HY	9.1	20	8.65...9.56	10	600	0.25	3	7
MMBZ5240BW	HZ	10	20	9.5...10.5	17	600	0.25	3	8
MMBZ5241BW	JA	11	20	10.45...11.55	22	600	0.25	2	8.4
MMBZ5242BW	JB	12	20	11.4...12.6	30	600	0.25	1	9.1
MMBZ5243BW	JC	13	9.5	12.35...13.65	13	600	0.25	0.5	9.9
MMBZ5245BW	JD	15	8.5	14.25...15.75	16	600	0.25	0.1	11
MMBZ5246BW	JE	16	7.8	15.2...16.8	17	600	0.25	0.1	12
MMBZ5248BW	JF	18	7	17.1...18.9	21	600	0.25	0.1	14
MMBZ5250BW	JH	20	6.2	19...21	25	600	0.25	0.1	15
MMBZ5251BW	JJ	22	5.6	20.9...23.1	29	600	0.25	0.1	17
MMBZ5252BW	JK	24	5.2	22.8...25.2	33	600	0.25	0.1	18
MMBZ5254BW	JM	27	5	25.65...28.35	41	600	0.25	0.1	21
MMBZ5256BW	JN	30	4.2	28.5...31.5	49	600	0.25	0.1	23
MMBZ5257BW	JP	33	3.8	31.35...34.65	58	700	0.25	0.1	25
MMBZ5258BW	JR	36	3.4	34.2...37.8	70	700	0.25	0.1	27
MMBZ5259BW	JX	39	3.2	37.05...40.95	80	800	0.25	0.1	30

¹⁾ Tested with pulses $t_p = 20\text{ ms}$.



SEMTECH ELECTRONICS LTD.

(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)



ISO/TS 16949 : 2002
Certificate No. 05103



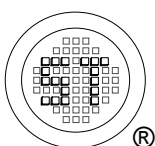
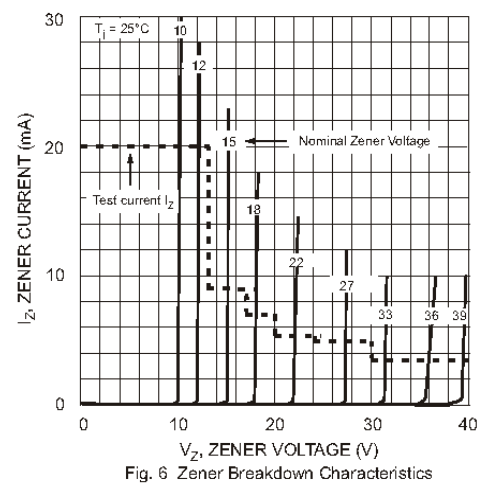
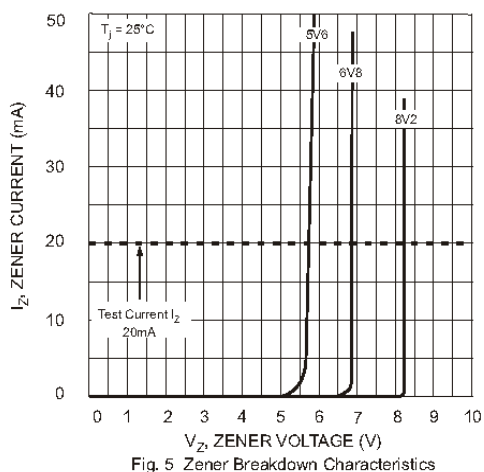
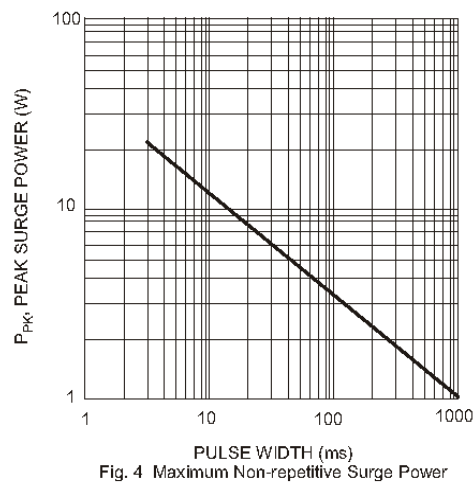
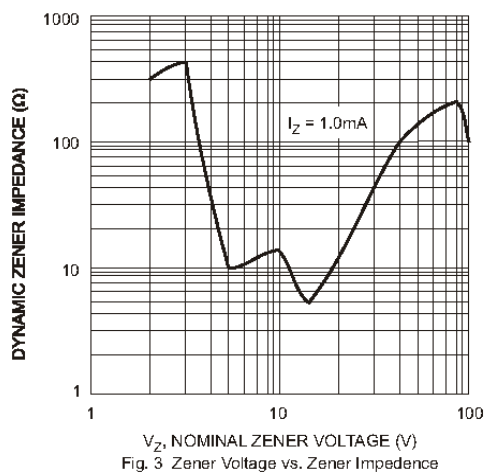
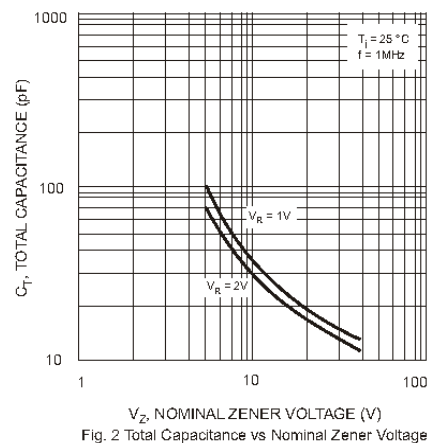
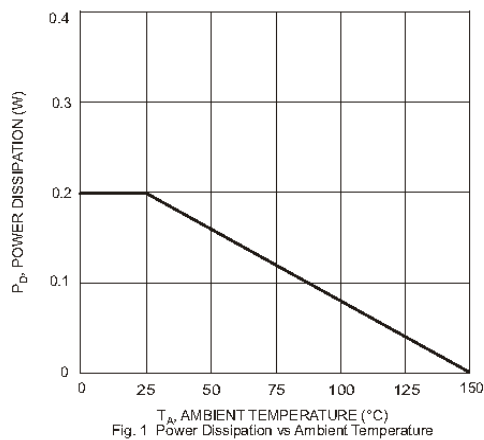
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Dated : 06/04/2007

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